KA1L0880B/KA1M0880B

Fairchild Power Switch(SPS)

Features

- Precision fixed operating frequency
- KA1L0880B(50KHz),KA1M0880B(67KHz)
- Pulse by pulse over current limiting
- Over load protection
- Over voltage protection (Min. 23V)
- Internal thermal shutdown function
- Under voltage lockout
- Internal high voltage sense FET
- Latch up mode
- Soft start

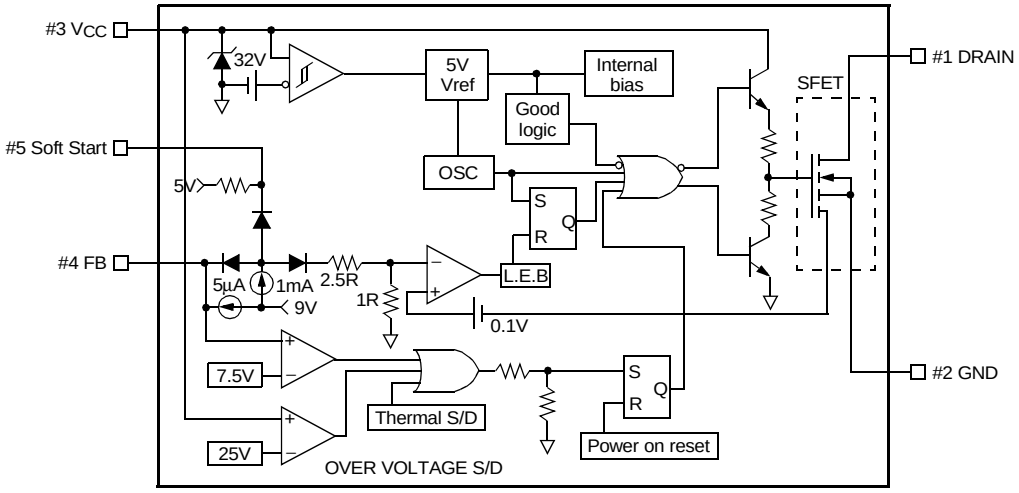
Description

The SPS product family is specially designed for an off-line SMPS with minimal external components. The SPS consist of high voltage power SenseFET and current mode PWM Controller IC. PWM controller features integrated fixed oscillator, under voltage lock out, leading edge blanking, optimized gate turn-on/turn-off driver, thermal shut down protection, over voltage protection, temperature compensated precision current sources for loop compensation and fault protection circuit. Compared to discrete MOSFET and controller or RCC switching converter solution, a SPS can reduce total component count, design size, weight and at the same time increase & efficiency, productivity, and system reliability. It has a basic platform well suited for cost effective design in either a flyback converter or a forward converter.

TO-3P-5L

1. DRAIN 2. GND 3. V_{CC} 4. FB 5. S/S

Internal Block Diagram



Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Drain-source (GND) voltage (1)	V_{DSS}	800	V
Drain-Gate voltage (R_{GS}=1MΩ)	V_{DGR}	800	V
Gate-source (GND) voltage	V_{GS}	±30	V
Drain current pulsed (2)	I_{DM}	32.0	A_{DC}
Single pulsed avalanche energy (3)	E_{AS}	810	mJ
Avalanche current (4)	I_{AS}	15	A
Continuous drain current (T_C=25°C)	I_D	8.0	A_{DC}
Continuous drain current (T_C=100°C)	I_D	5.6	A_{DC}
Supply voltage	V_{CC}	30	V
Analog input voltage range	V_{FB}	–0.3 to V_{SD}	V
Total power dissipation	P_D	190	W
	Derating	1.54	W/°C
Operating temperature	T_{OPR}	–25 to +85	°C
Storage temperature	T_{STG}	–55 to +150	°C

Notes:

1. Tj=25°C to 150°C
2. Repetitive rating: Pulse width limited by maximum junction temperature
3. L=24mH, V_{DD}=50V, R_G=25Ω, starting Tj=25°C
4. L=13μH, starting Tj=25°C

Electrical Characteristics (SFET part)

(Ta=25°C unless otherwise specified)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Drain-source breakdown voltage	BV_{DSS}	V_{GS}=0V, I_D=50μA	800	-	-	V
Zero gate voltage drain current	I_{DSS}	V_{DS}=Max., Rating, V_{GS}=0V	-	-	50	μA
		V_{DS}=0.8Max., Rating, V_{GS}=0V, T_C=125°C	-	-	200	μA
Static drain-source on resistance (note)	$R_{DS(ON)}$	V_{GS}=10V, I_D=5.0A	-	1.2	1.5	Ω
Forward transconductance (note)	gfs	V_{DS}=15V, I_D=5.0A	1.5	2.5	-	S
Input capacitance	Ciss	V_{GS}=0V, V_{DS}=25V, f=1MHz	-	2460	-	pF
Output capacitance	Coss		-	210	-	
Reverse transfer capacitance	Crss		-	64	-	
Turn on delay time	td(on)	V_{DD}=0.5BV_{DSS}, I_D=8.0A (MOSFET switching time are essentially independent of operating temperature)	-	-	90	nS
Rise time	tr		-	95	200	
Turn off delay time	td(off)		-	150	450	
Fall time	tf		-	60	150	
Total gate charge (gate-source+gate-drain)	Qg	V_{GS}=10V, I_D=8.0A, V_{DS}=0.5BV_{DSS} (MOSFET switching time are essentially independent of operating temperature)	-	-	150	nC
Gate-source charge	Qgs		-	20	-	
Gate-drain (Miller) charge	Qgd		-	70	-	

Note:

Pulse test: Pulse width ≤ 300μS, duty cycle ≤ 2%

$S = \frac{1}{R}$

Electrical Characteristics (CONTROL part)

(Ta=25°C unless otherwise specified)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
REFERENCE SECTION						
Output voltage (1)	Vref	Ta=25°C	4.80	5.00	5.20	V
Temperature Stability (1)(2)	Vref/ΔT	–25°C≤Ta≤+85°C	-	0.3	0.6	mV/°C
OSCILLATOR SECTION						
Initial accuracy	F_{OSC}	**KA1L0880B**	45	50	55	kHz
		KA1M0880B	61	67	73	
Frequency change with temperature (2)	ΔF/ΔT	–25°C≤Ta≤+85°C	-	±5	±10	%
PWM SECTION						
Maximum duty cycle	Dmax		74	77	80	%
FEEDBACK SECTION						
Feedback source current	I_{FB}	Ta=25°C, 0V≤Vfb≤3V	0.7	0.9	1.1	mA
Shutdown delay current	Idelay	Ta=25°C, 5V≤Vfb≤V_{SD}	4.0	5.0	6.0	μA
OVER CURRENT PROTECTION SECTION						
Over current protection	I_L(max)	Max. inductor current	4.40	5.00	5.60	A
UVLO SECTION						
Start threshold voltage	Vth(H)	-	14	15	16	V
Minimum operating voltage	Vth(L)	After turn on	9	10	11	V
TOTAL STANDBY CURRENT SECTION						
Start current	I_{ST}	V_{CC}=14V	0.1	0.3	0.45	mA
Operating supply current (control part only)	I_{OPR}	Ta=25°C	6	12	18	mA
V_{CC} zener voltage	V_Z	I_{CC}=20mA	30	32.5	35	V
SHUTDOWN SECTION						
Shutdown Feedback voltage	V_{SD}	-	6.9	7.5	8.1	V
Thermal shutdown temperature (Tj) (1)	T_{SD}	-	140	160	-	°C
Over voltage protection voltage	V_{OVP}	-	23	25	28	V

Notes:

1. These parameters, although guaranteed, are not 100% tested in production
2. These parameters, although guaranteed, are tested in EDS (wafer test) process

Typical Performance Characteristics

(These characteristic graphs are normalized at Ta=25°C)

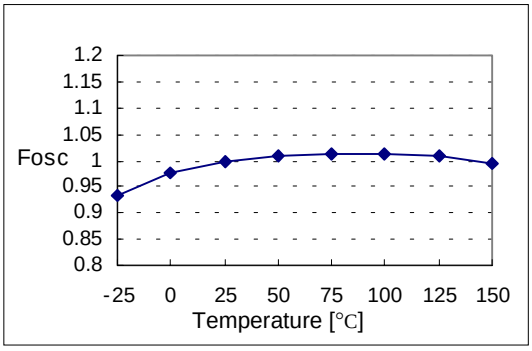


Figure 1. Operating Frequency

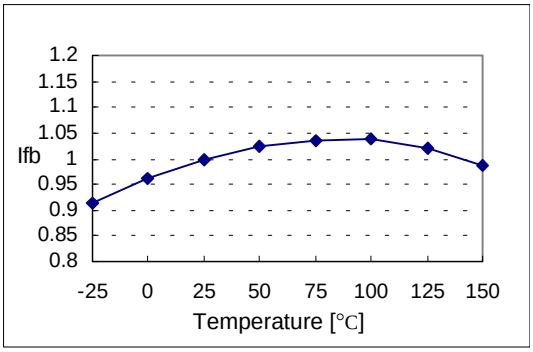


Figure 2. Feedback Source Current

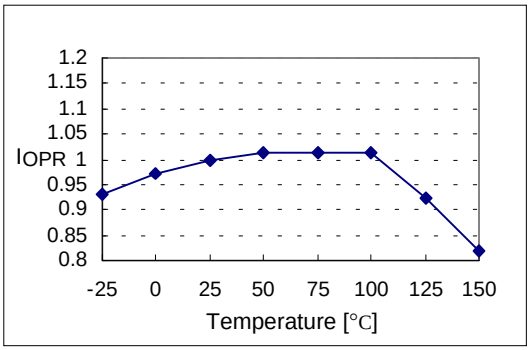


Figure 3. Operating Current

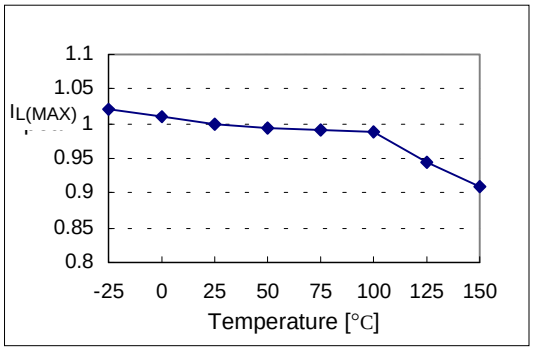


Figure 4. Max. Inductor Current

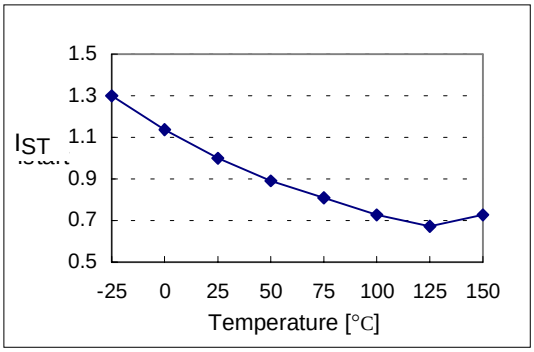


Figure 5. Start up Current

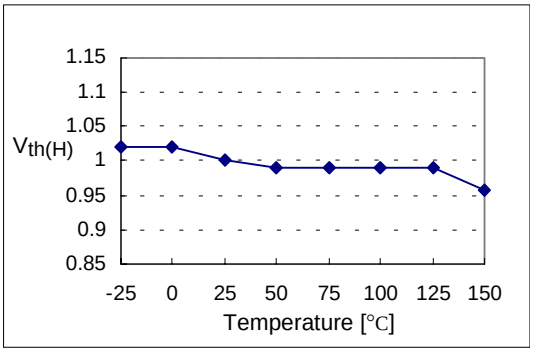


Figure 6. Start Threshold Voltage

Typical Performance Characteristics (Continued)

(These characteristic graphs are normalized at Ta=25°C)

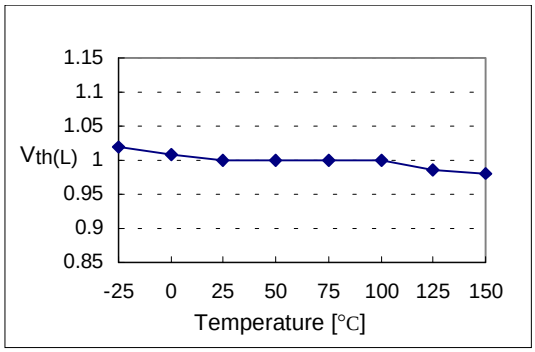


Figure 7. Stop Threshold Voltage

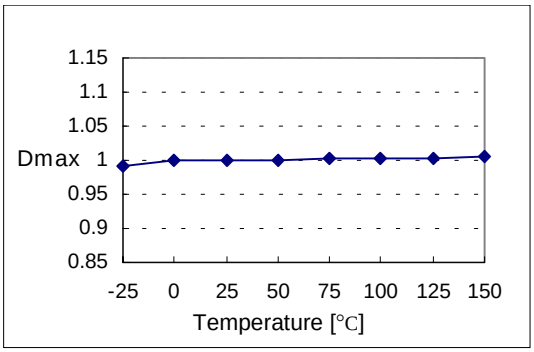


Figure 8. Maximum Duty Cycle

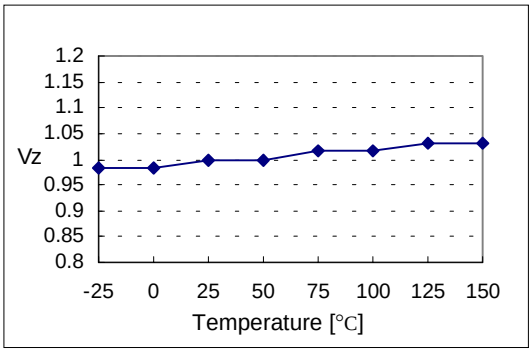


Figure 9. V_{CC} Zener Voltage

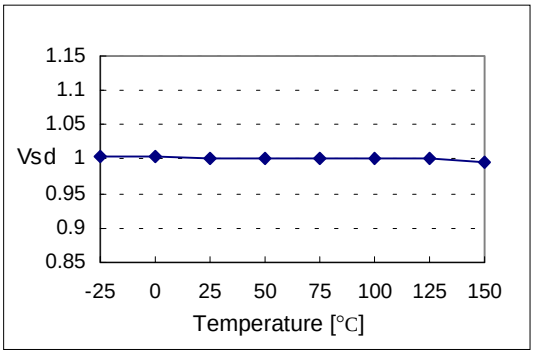


Figure 10. Shutdown Feedback Voltage

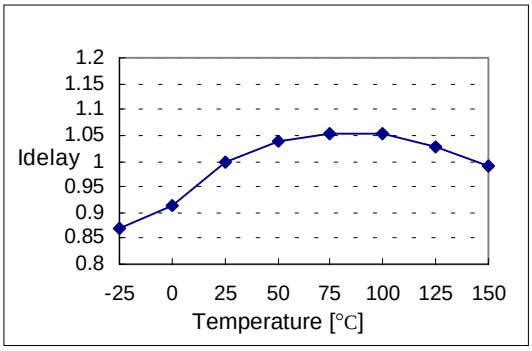


Figure 11. Shutdown Delay Current

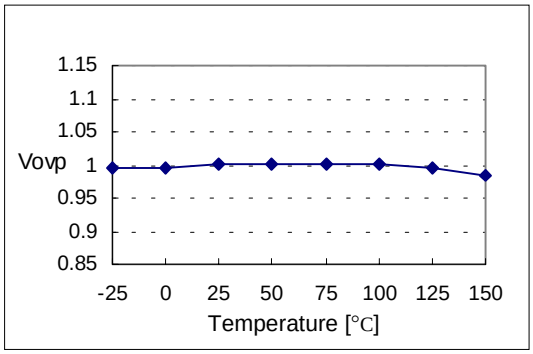


Figure 12. Over Voltage Protection

Typical Performance Characteristics (Continued)

(These characteristic grahps are normalized at Ta=25°C)

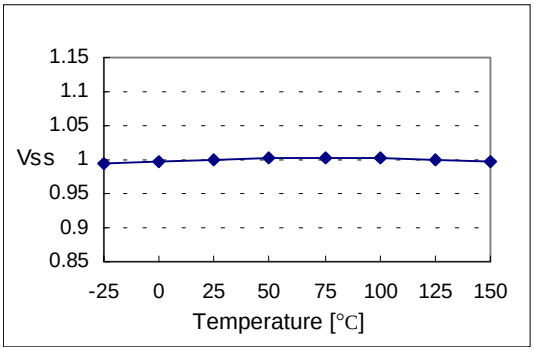


Figure 13. Soft Start Voltage

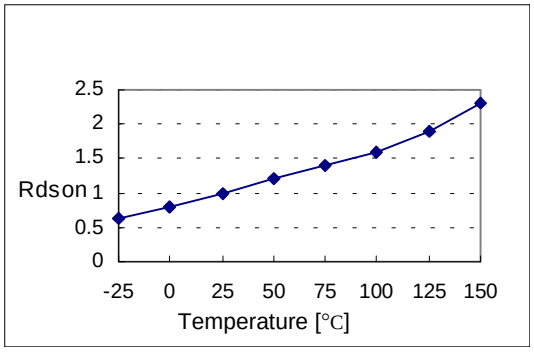
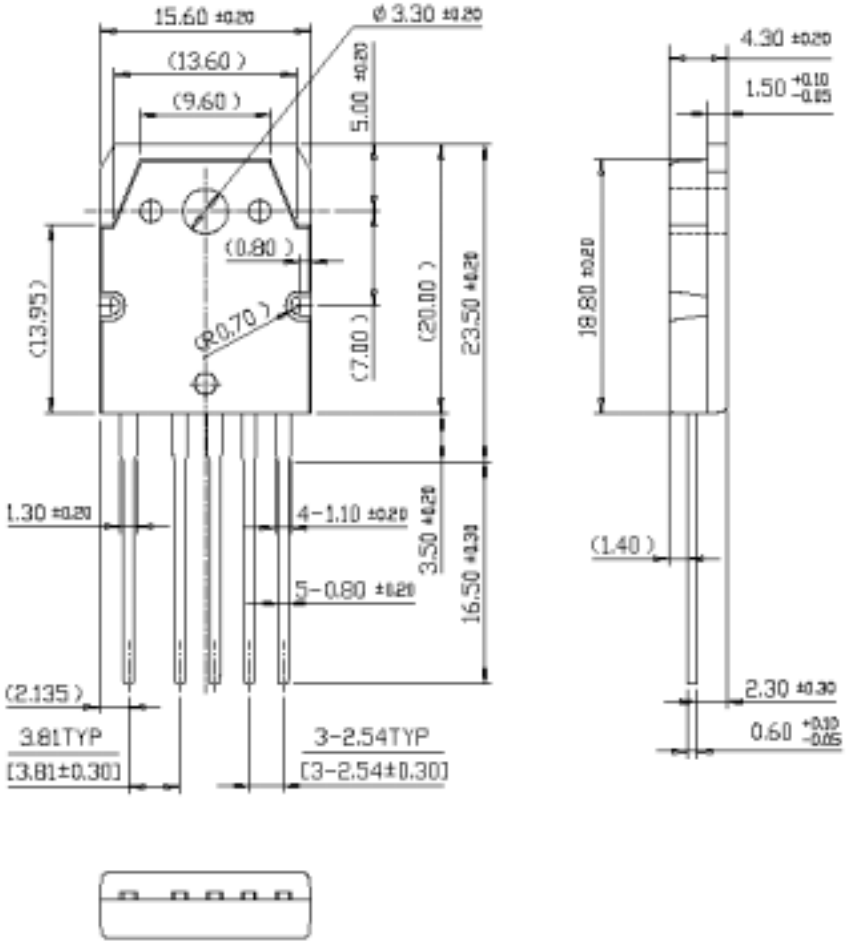


Figure 14. Drain Source Turn-on Resistance

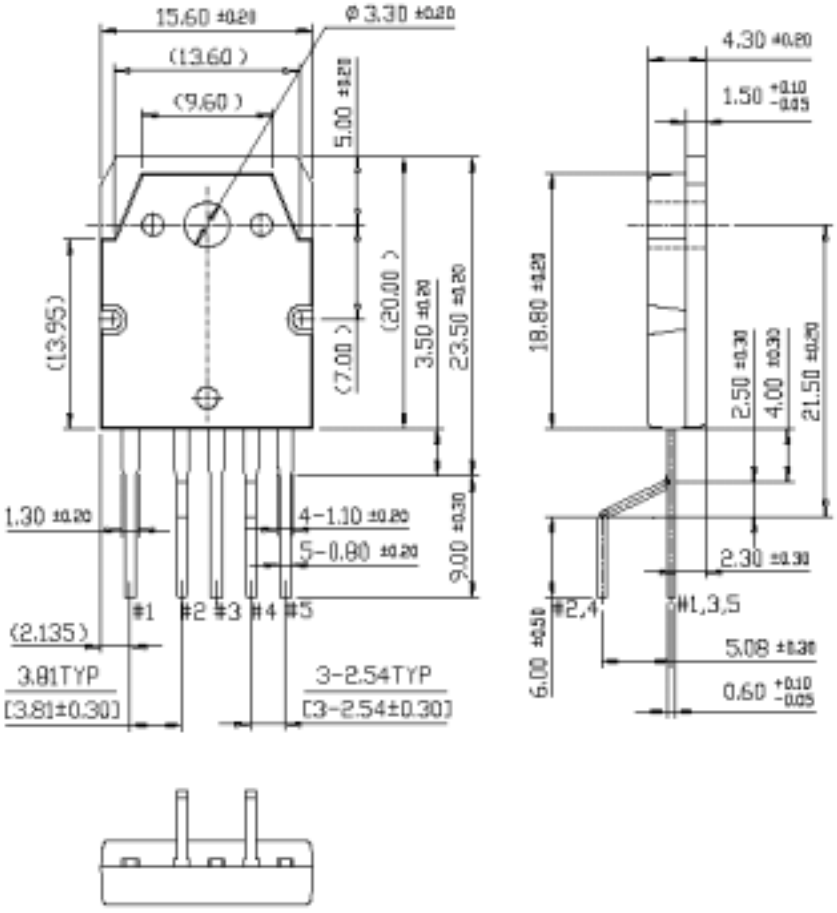
Package Dimensions

TO-3P-5L



Package Dimensions

TO-3P-5L (Forming)



Ordering Information

Product Number	Package	Rating	Fosc
KA1L0880B-TU	TO-3P-5L	800V, 8A	50kHz
KA1L0880B-YDTU	TO-3P-5L(Forming)		
KA1M0880B-TU	TO-3P-5L	800V, 8A	67kHz
KA1M0880B-YDTU	TO-3P-5L(Forming)		

TU : Non Forming Type
YDTU : Forming type

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